

30

N-Channel 30 V (D-S) MOSFET

15.9 nC

PRODUCT SUMMARY $R_{DS(on)}(m\Omega)(Typ.)$ Q_g (Typ.) V_{DS} (V) I_D (A)^a 19 at $V_{GS} = 10 \text{ V}$

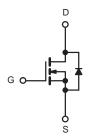
21 at $V_{GS} = 4.5 \text{ V}$

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- High Current Capability
- RoHS and Halogen-Free Compliant

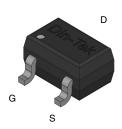
APPLICATIONS

- DC/DC Converters in Computing
- Isolated DC/DC Converters in Telecom and Industrial



N-Channel MOSFET

SOT-23-3L Pin Configuration Top View



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V _{GS}	± 20	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Continuous Drain Current /T 450 °C\2	T _C = 25 °C	,	6	
Continuous Drain Current (T _J = 150 °C) ^a	T _C = 100 °C	I _D	4	А
Pulsed Drain Current ^b		I _{DM}	18	
Maximum Davier Discinsting	T _C = 25 °C	D	1.7	W
Maximum Power Dissipation ^c	T _C = 100 °C	P _D	0.7	
Operating Junction and Storage Temperature Ra	nge	T _J , T _{stg}	-50 to 150	°C

THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	115	°C/W	
Junction-to-Case (Drain)	R _{thJC}	73.5	J C/VV	

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of R_{0JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30	-	-	- ,,	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		-	1.5	1.5 V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
Zara Oata Wallana Baria Oaraa		$V_{DS} = 30 V, V_{GS} = 0 V$	-	-	1	μА	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 24 V, V _{GS} = 0 V, T _J = 55 °C	-	-	10		
On-State Drain Current ^a	I _{D(on)}	V _{DS} ≥ 5 V, V _{GS} = 10 V	6	-	-	Α	
Drain Course On State Registered 3	D	V _{GS} = 10 V, I _D = 3 A	-	19	24	0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 3 A	-	21	33	mΩ	
Forward Transconductance ^a	9fs	V _{DS} = 15 V, I _D = 3 A	-	11	-	S	
Dynamic ^b			•	•			
Input Capacitance	C _{iss}		-	693	-	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 15 \text{ V}, f = 1 \text{ MHz}$	-	59	-		
Reverse Transfer Capacitance	C _{rss}		-	51	-		
Total Gate Charge ^c	Q_g		-	15.9	-		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 3\text{A}$	-	0.82	-	nC	
Gate-Drain Charge ^c	Q _{gd}		-	0.62	-		
Gate Resistance	R _g	f = 1 MHz	-	3.8	-	Ω	
Turn-On Delay Time ^c	t _{d(on)}		-	5	-		
Rise Time ^c	t _r	$V_{DD} = 15 \text{ V}, I_D = 3 \text{ A}, R_g = 1 \Omega$	-	12	=		
Turn-Off Delay Time ^c	t _{d(off)}	V_{GS} = 10 V , R_L = 5.6 Ω	-	10	-	ns	
Fall Time ^c	t _f		-	5	-		
Drain-Source Body Diode Ratings and	Characterist	ics ^b (T _C = 25 °C)					
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	-	-	6	Α	
Pulsed Current	I _{SM}		-	-	18	Α	
Forward Voltage ^a	V _{SD}	I _F = 1 A, V _{GS} = 0 V	-	0.78	=	V	
Reverse Recovery Time	t _{rr}	I _F = 3 A, di/dt = 100 A/µs	-	10	-	ns	
Reverse Recovery Charge	Q _{rr}	i _F = 3 A, αί/αι – 100 A/μS	-	5	-	nC	

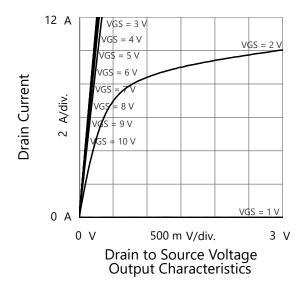
Notes

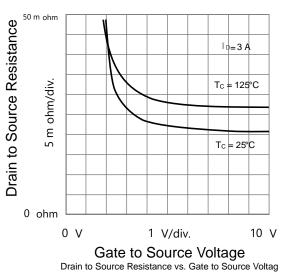
- a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

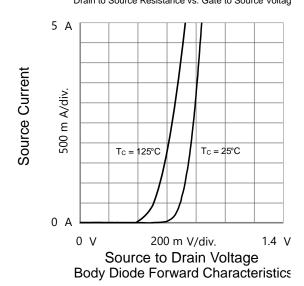
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those in dicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended pe riods may affect device reliability.

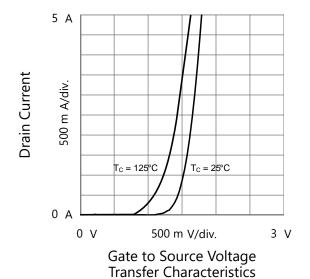


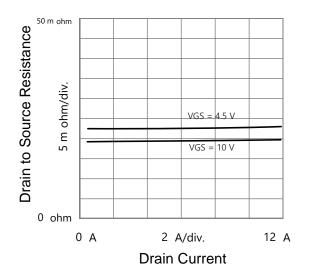
TYPICAL CHARAC TERISTICS (25 °C. unless otherwise noted)

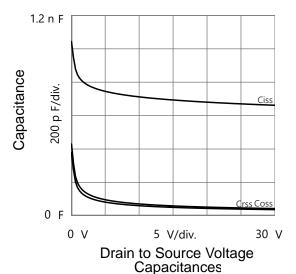






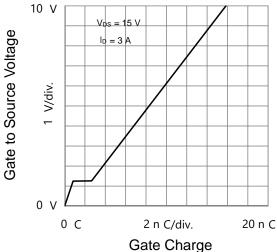




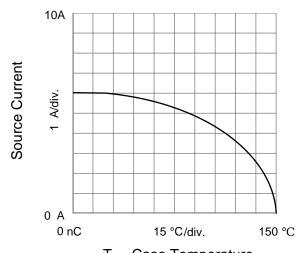




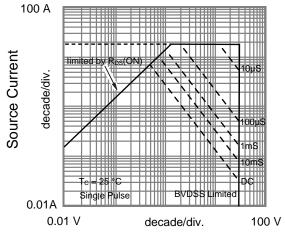
TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)



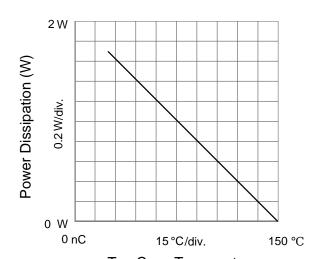




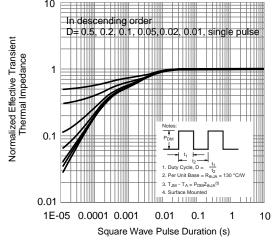
T_C - Case Temperature



Source to Drain Voltage Safe Operating Area, Junction-to-Case



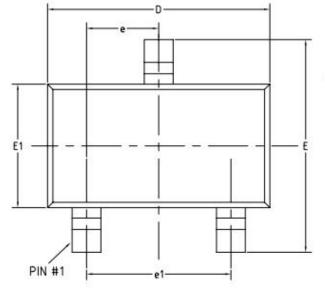
T_C - Case Temperature

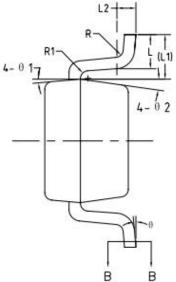


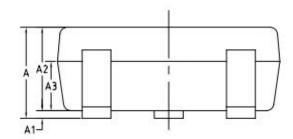
Normalized Thermal Transient Impedance



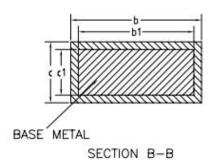
SOT-23-3L PACKAGE OUTLINE







COMMON DIMENSIONS (UNITS OF MEASURE= MILLIMETER)



SYMBOL	MIN	TYP	MAX	
Α	-	-	1.50	
A1	0.00	-	0.18	
A2	0.85	1.10	1.35	
А3	0.58	0.65	0.72	
b	0.23		0.53	
b1	0.20	0.40	0.50	
С	0.09	-	0.22	
c1	0.08	0.13	0.21	
D	2.78	2.95	3.10	
Е	2.58	2.80	3.03	
E1	1.55	1.65	1.78	
е	0.83	0.95	1.07	
e1	1.78	1.90	2.02	
L	0.28	0.45	0.62	
L1	0.59REF			
L2	0.25BSC			
R	0.04		-	
R1	0.04	-	0.21	
θ	0°	-	8°	
θ1	8°	10°	12°	
θ2	8°	10°	12°	





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